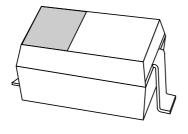
DISCRETE SEMICONDUCTORS

DATA SHEET



PMEG1020EAUltra low V_F MEGA Schottky barrier diode

Preliminary specification

2003 Mar 07





PMEG1020EA

FEATURES

Forward current: 2 AReverse voltage: 10 VUltra low forward voltage

· Very small plastic SMD package.

APPLICATIONS

- · Low voltage rectification
- High efficiency DC/DC conversion
- · Switch mode power supply
- · Inverse polarity protection
- Low power consumption applications.

DESCRIPTION

Planar Maximum Efficiency General Application (MEGA) Schottky barrier diode with an integrated guard ring for stress protection, encapsulated in a SOD323 (SC-76) very small SMD plastic package.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | cathode |
| 2 | anode |

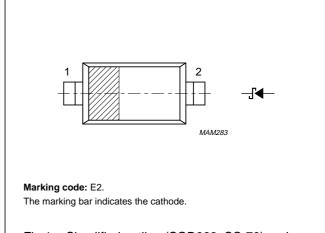


Fig.1 Simplified outline (SOD323; SC-76) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|--|------|------|------|
| V _R | continuous reverse voltage | | _ | 10 | V |
| I _F | continuous forward current | T _{sp} ≤ 55 °C | _ | 2 | Α |
| I _{FRM} | repetitive peak forward current | $t_p \le 1 \text{ ms}; \ \delta \le 0.5$ | _ | 3.2 | Α |
| I _{FSM} | non-repetitive peak forward current | t _p = 8 ms square wave | _ | 9 | Α |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | TYP. | MAX. | UNIT |
|----------------|-------------------|--|------|------|------|
| V _F | forward voltage | see Fig.2; note 1 | | | |
| | | I _F = 0.01 A | 100 | 130 | mV |
| | | I _F = 0.1 A | 170 | 200 | mV |
| | | I _F = 1 A | 280 | 350 | mV |
| | | I _F = 2 A | 350 | 460 | mV |
| I _R | reverse current | see Fig.3; note 2 | | | |
| | | V _R = 5 V | 0.7 | 2 | mA |
| | | V _R = 8 V | 1 | 2.5 | mA |
| | | V _R = 10 V | 1.2 | 3 | mA |
| C _d | diode capacitance | V _R = 5 V; f = 1 MHz; see Fig.4 | 37 | 45 | pF |

Notes

- 1. Pulse test: $t_p = 300 \,\mu s$; $\delta = 0.02$.
- 2. For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses (P_R) are a significant part of the total power losses.

THERMAL CHARACTERISTICS

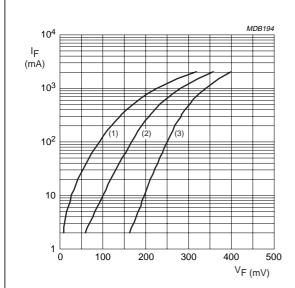
| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|--|------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 450 | K/W |
| | | note 2 | 210 | K/W |
| R _{th j-s} | thermal resistance from junction to solder point | note 3 | 90 | K/W |

Notes

- 1. Refer to SOD323 (SC-76) standard mounting conditions.
- 2. Device mounted on an FR4 printed-circuit board with copper clad 10 x 10 mm.
- 3. Solder point of cathode tab.

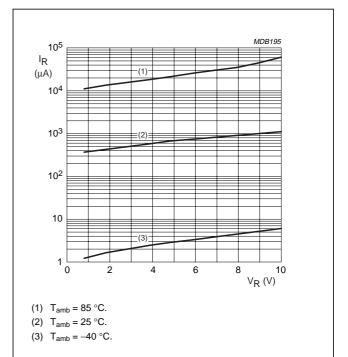
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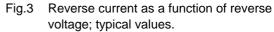
GRAPHICAL DATA



- (1) $T_{amb} = 85 \,^{\circ}C$.
- (2) $T_{amb} = 25 \,^{\circ}C$.
- (3) $T_{amb} = -40 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.





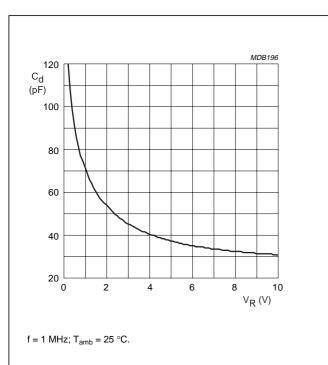


Fig.4 Diode capacitance as a function of reverse voltage; typical values.

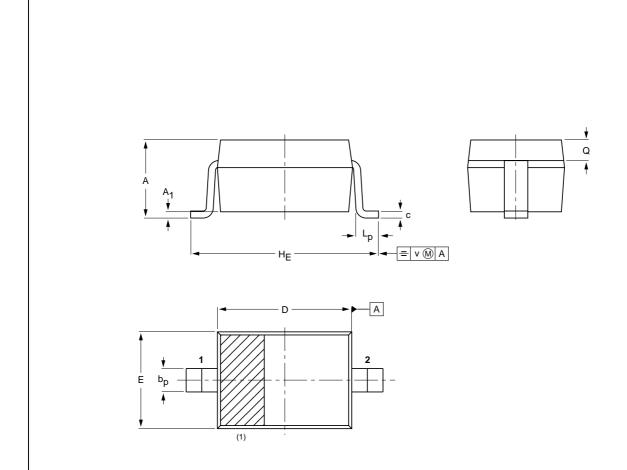
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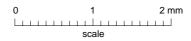
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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD323





DIMENSIONS (mm are the original dimensions)

| UNIT | A | A ₁ max. | bp | С | D | E | HE | Lp | Q | v |
|------|------------|---------------------|----|--------------|------------|--------------|------------|--------------|--------------|-----|
| mm | 1.1 0.8 | + 0.05 - 0.05 | | 0.25 0.10 | 1.8 1.6 | 1.35 1.15 | 2.7 2.3 | 0.45 0.15 | 0.25 0.15 | 0.2 |

Note

1. The marking bar indicates the cathode.

| OUTLINE | OUTLINE REFERENCES | | | | | ISSUE DATE | |
|-------------|--------------------|-------|-------|--|------------|---------------------------------|--|
| VERSION IEC | | JEDEC | EIAJ | | PROJECTION | ISSUE DATE | |
| SOD323 | | | SC-76 | | | 98-09-14 99-09-13 | |

Philips Semiconductors Preliminary specification

Ultra low V_F MEGA Schottky barrier diode

PMEG1020EA

DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS(2)(3) | DEFINITION |
|-------|-------------------------------------|-------------------------|--|
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